

<b>Notice of References Cited</b>	Application/Control No.	Applicant(s)/Patent Under Reexamination KENJI KOHIRO
	Examiner	Art Unit 1722

**U.S. PATENT DOCUMENTS**

*	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
A	US-			
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C	US-			
D	US-			
E	US-			
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**FOREIGN PATENT DOCUMENTS**

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**NON-PATENT DOCUMENTS**

*	Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)		
U	D. Keiper, et al., Metal organic vapor-phase epitaxy (MOVPE) growth of InP and InGaAs usin tertiarybutylarsine (TBA) and tertiarybutylphosphine (TBP) in N2 ambient. JOURNAL OF CRYSTAL GROWTH, Vol. 204, 1999, pages 256-262.		
V			
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\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
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